



Ultrasoft Recovery Bridge



Note:

- 1.The silk screen is WR8M;
- 2.YXWWH means to produce $\ LOT_{\circ}$

Features

- Low profile space
- · Ideal for printed circuit board
- Low reverse leakage
- Ultrafast reverse recovery time
- · Applicated in power supply equipment
- High ring wave immunity capability

Benefits

- Case: NBS
- Terminals: Solderable Per MIL-STD-750
- Approx. Weight: 82mg 0.0029oz

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	WR8M	Units
Maximum Repetitive Peak Reverse Voltage	VRRM	1000	V
Maximum RMS voltage	VRMS	700	V
Maximum DC Blocking Voltage	VDC	1000	V
Average Rectified Output Current	lo	0.8	А
Reverse Recovery Time. IF=0.5A,IR=1A,IRR=0.25A	Trr	10	us
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	25	A
$I^{2}t$ rating for fusing (1ms< t < 10ms)	I²t	2.6	A ² S
Maximum Forward Voltage at 0.4 A	VF	1.1	V
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	IR	5 100	μA
Typical Junction Capacitance (Note1)	Cj	82	pF
Operating and Storage Temperature Range	Tj, T _{stg}	-55 ~ +150	°C
Typical thermal resistance (Note 2)	RthJL RthJA	35 180	°C/W

Note: 1. Measured at 1MHz and applied reverse voltage of 4 VDC.

2. Thermal resistance junction to case, lead and ambient in accordance with JESD-51.

Unit mounted on glass-epoxy substrate with 1oz/ft2_20x20 mm copper pad per pin with heatsink











